## NSN 5961-01-159-6667

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View Online at https://aerobasegroup.com/nsn/5961-01-159-6667 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 

N/a

Shelf Life:

**Unit Of Measure:** 

2 uninsulated wire lead and 1 case

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